ESD Protection Diode

Dual Common Anode

These dual monolithic silicon ESD protection diodes are intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. Their dual junction common anode design protects two separate lines using only one package. These devices are ideal for situations where board space is at a premium.

Specification Features:

- SC-89 Package Allows Either Two Separate Unidirectional Configurations or a Single Bidirectional Configuration
- ESD Rating of Class N (exceeding 16 kV) per the Human Body Model
- Meets IEC61000-4-2 Level 4
- Low Leakage < 5.0 μA
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Mechanical Characteristics:

CASE: Void-free, Transfer-molded, Thermosetting Plastic Epoxy Meets UL 94, V–0

LEAD FINISH: 100% Matte Sn (Tin)

MOUNTING POSITION: Any

QUALIFIED MAX REFLOW TEMPERATURE:

260°C Device Meets MSL 1 Requirements



ON Semiconductor®

www.onsemi.com







L = Device Code x = Specific Device M = Date Code • = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
NZL5V6AXV3T1G	SC-89	3000/Tape & Reel
SZNZL5V6AXV3T1G	SC-89	3000/Tape & Reel
NZL6V8AXV3T1G	SC-89	3000/Tape & Reel
SZNZL6V8AXV3T1G	SC-89	3000/Tape & Reel
NZL6V8AXV3T3G	SC-89	10000/Tape & Reel
SZNZL6V8AXV3T3G	SC-89	10000/Tape & Reel
NZL7V5AXV3T1G	SC-89	3000/Tape & Reel
SZNZL7V5AXV3T1G	SC-89	3000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

DEVICE MARKING INFORMATION

See specific marking information in the device marking column of the table on page 2 of this data sheet.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Total Power Dissipation on FR–5 Board (Note 1) @ T _A = 25°C Derate above 25°C	PD	240 1.9	mW mW/°C
Thermal Resistance Junction to Ambient	R_{\thetaJA}	525	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C
Lead Solder Temperature – Maximum (10 Second Duration)	TL	260	°C
IEC61000-4-2 Contact IEC61000-4-2 Air	ESD	10 10	kV

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR–5 board with minimum recommended mounting pad.

*Other voltages may be available upon request.

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted)

UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or 2 and 3)

Symbol	Parameter				
V _{RWM}	Working Peak Reverse Voltage				
I _R	Maximum Reverse Leakage Current @ V _{RWM}				
V _{BR}	Breakdown Voltage @ I _T				
Ι _Τ	Test Current				
١ _F	Forward Current				
V _F	Forward Voltage @ I _F				



ELECTRICAL CHARACTERISTICS (T _A = 25°C unless otherwise noted, V _F = 0.9 V Max @ I _F = 10 mA for all types)
UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or Pins 2 and 3)

				E	Breakdown Voltage			Surge				
	Device	V _{RWM}	I _R @ V _{RWM}	V _{BF}	(Note 2)	(V)	@ Iz _T	V _C (V) @ I _{PP} = 1.0 A [†]	V _C (V) @ Max I _{PP} †	Max I _{PP} (A) [†]	P _{pk} (W) [†]	
Device	Marking	v	μΑ	Min	Nom	Max	mA	Тур	Мах		Тур	
NZL5V6AXV3T1	LO	3.0	5.0	5.32	5.6	5.88	5.0	7.0	10.1	4.8	50	
NZL6V8AXV3T1	L2	4.5	1.0	6.46	6.8	7.14	5.0	7.9	11.9	6.7	73	
NZL6V8AXV3T3	L2	4.5	1.0	6.46	6.8	7.14	5.0	7.9	11.9	6.7	73	
NZL7V5AXV3T1	L3	5.0	1.0	7.12	7.5	7.88	5.0	8.8	13.5	5.7	75	

2. V_{BR} measured at pulse test current I_T at an ambient temperature of 25°C.

† Surge current waveform per Figure 5.

TYPICAL CHARACTERISTICS



(Upper curve for each part is unidirectional mode, lower curve is bidirectional mode)

100

90

80



PEAK VALUE $I_{RSM} \ensuremath{@} 8 \ensuremath{\,\mu s}$

PULSE WIDTH (tp) IS DEFINED

AS THAT POINT WHERE THE

Figure 5. 8 x 20 µs Pulse Waveform



TYPICAL COMMON ANODE APPLICATIONS

A dual junction common anode design in an SC-89 package protects two separate lines using only one package. This adds flexibility and creativity to PCB design especially

when board space is at a premium. Two simplified examples of surge protection applications are illustrated below.



Figure 8. Computer Interface Protection





DATE 31 JUL 2003



SCALE 4:1





STYLE 1: PIN 1. BASE 2. EMITTER 3. COLLECTOR

STYLE 2: PIN 1. ANODE 2. N/C 3. CATHOD-Е





SC-89, 3 LEAD CASE 463C-03 **ISSUE C**

н

RECOMMENDED PATTERN OF SOLDER PADS

- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETERS
- 2. OOKTIGETING DIMENSION INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MINIMUM THICKNESS OF BASE MATERIAL.
- 4. 463C-01 OBSOLETE, NEW STANDARD 463C-02.

	MIL	LIMETE	ERS	INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	1.50	1.60	1.70	0.059	0.063	0.067	
в	0.75	0.85	0.95	0.030	0.034	0.040	
С	0.60	0.70	0.80	0.024	0.028	0.031	
D	0.23	0.28	0.33	0.009	0.011	0.013	
G	0	.50 BSC)	0.020 BSC			
Н	C).53 REF	-	0.021 REF			
J	0.10	0.15 0.20		0.004	0.006	0.008	
ĸ	0.30	0.40	0.50	0.012	0.016	0.020	
L	1.10 REF			0.043 REF			
м		10					
Ν			10 -			10	
S	1.50	1.60	1.70	0.059	0.063	0.067	

GENERIC **MARKING DIAGRAM***



xx = Specific Device Code D = Date Code

*This information is generic. Please refer to device data sheet for actual part marking.

DOCUMENT NUMBER:	98AON11472D Electronic versions are uncontrolled except when accessed directly from the Document Reposito Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	SC-89, 3 LEAD		PAGE 1 OF 1	
ON Semiconductor reserves the right the suitability of its products for any pa	to make changes without further notice to an articular purpose, nor does ON Semiconducto	stries, LLC dba ON Semiconductor or its subsidiaries in the United States y products herein. ON Semiconductor makes no waranty, representation r assume any liability arising out of the application or use of any product or cidental damages. ON Semiconductor does not convey any license under	or guarantee regarding r circuit, and specifically	

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and calcular performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

TECHNICAL SUPPORT

onsemi Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative